

## N-Channel 150 V (D-S) MOSFET

### PRODUCT SUMMARY

| $V_{DS}$ (V) | $R_{DS(on)}$ (m $\Omega$ )(Typ.) | $I_D$ (A) | $Q_g$ (Typ.) |
|--------------|----------------------------------|-----------|--------------|
| 150          | 52 at $V_{GS} = 10$ V            | 25        | 9            |

### FEATURES

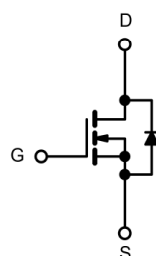
- DT-Trench Power MOSFET
- 100 %  $R_g$  and UIS Tested

### APPLICATIONS

- DC/DC Converters
- DC/AC Inverters
- Motor Drives



TO-263



N-Channel MOSFET

### ABSOLUTE MAXIMUM RATINGS ( $T_C = 25$ °C, unless otherwise noted)

| Parameter  | Symbol         | Limit                      | Unit |
|--|----------------|----------------------------|------|
| Drain-Source Voltage                             | $V_{DS}$       | 150                        | V    |
| Gate-Source Voltage                              | $V_{GS}$       | $\pm 20$                   |      |
| Continuous Drain Current                         | $I_D$          | $T_C = 25$ °C              | A    |
|  |                | $T_C = 70$ °C              |      |
| Pulsed Drain Current ( $t = 300$ $\mu$ s)        | $I_{DM}$       | 80                         |      |
| Avalanche Current                                | $I_{AS}$       | 22                         |      |
| Single Avalanche Energy <sup>a</sup>             | $E_{AS}$       | 35                         | mJ   |
| Maximum Power Dissipation <sup>a</sup>           | $P_D$          | $T_C = 25$ °C              | W    |
|  |                | $T_A = 25$ °C <sup>c</sup> |      |
| Operating Junction and Storage Temperature Range | $T_J, T_{stg}$ | - 55 to 150                | °C   |

### THERMAL RESISTANCE RATINGS

| Parameter                                    | Symbol     | Limit | Unit |
|--|------------|-------|------|
| Junction-to-Ambient (PCB Mount) <sup>c</sup> | $R_{thJA}$ | 50    | °C/W |
| Junction-to-Case (Drain)                     | $R_{thJC}$ | 1.5   |      |

Notes:

a. Duty cycle  $\leq 1$  %.

b. See SOA curve for voltage derating.

c. When mounted on 1" square PCB (FR-4 material).

d. Base on  $T_C = 25$  °C.

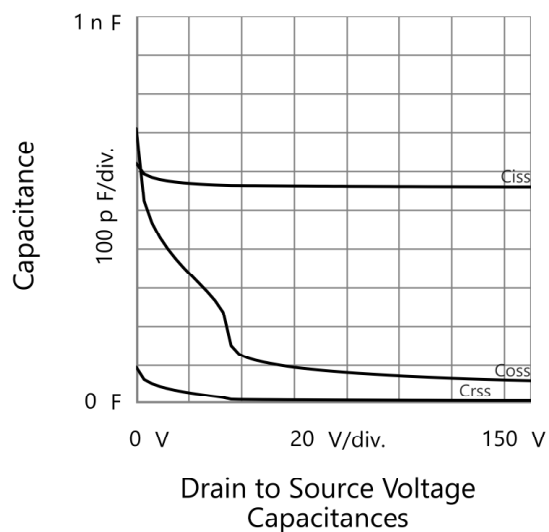
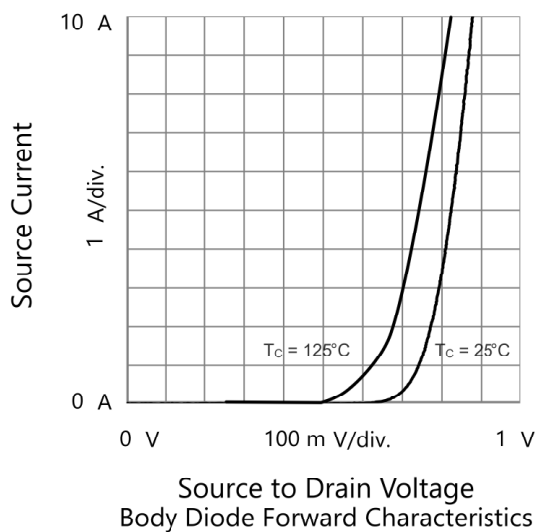
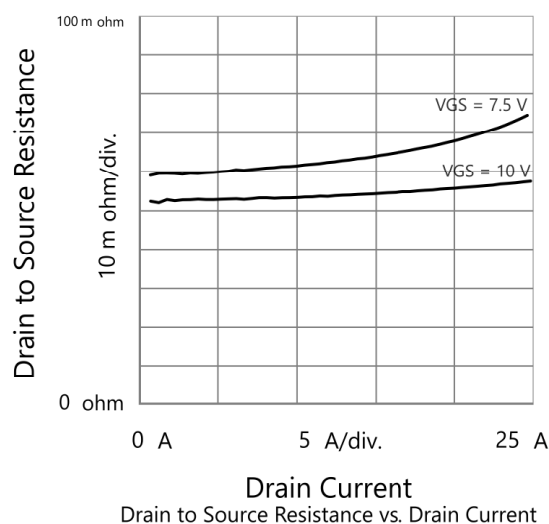
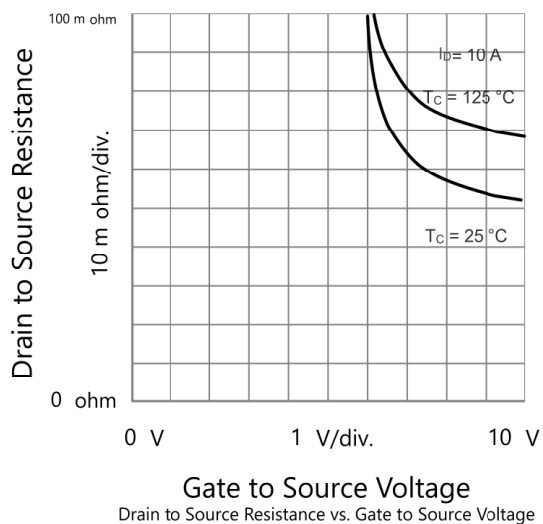
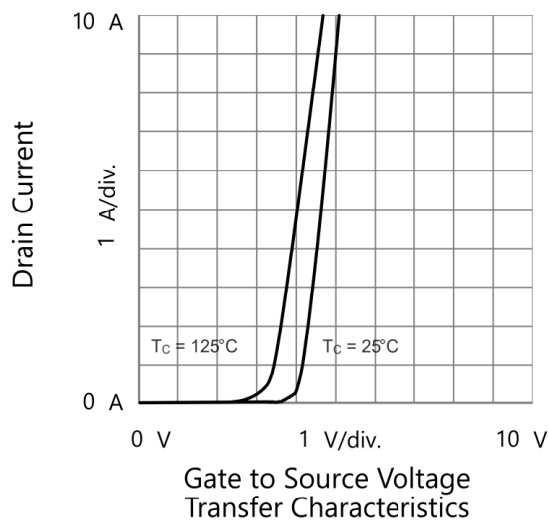
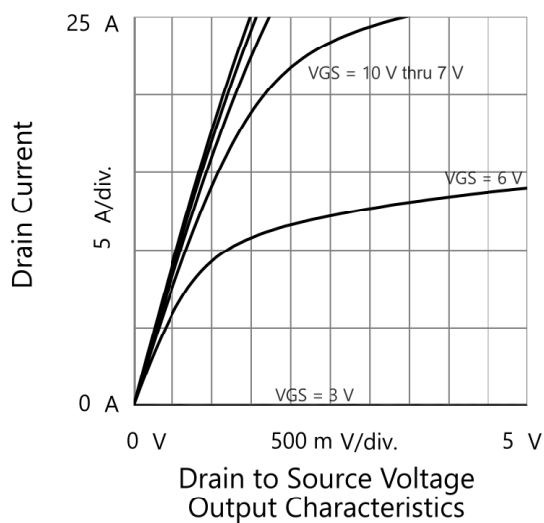
| SPECIFICATIONS (T <sub>J</sub> = 25 °C, unless otherwise noted)                         |                     |  |      |      |       |      |
|---|---------------------|--|------|------|-------|------|
| Parameter   | Symbol              | Test Conditions  | Min. | Typ. | Max.  | Unit |
| Static  |                     |  |      |      |       |      |
| Drain-Source Breakdown Voltage  | V <sub>DS</sub>     | V <sub>GS</sub> = 0 V, I <sub>D</sub> = 250 μA   | 150  |      |       | V    |
| Gate Threshold Voltage  | V <sub>GS(th)</sub> | V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 250 μA  | 1.5  |      | 4     |      |
| Gate-Body Leakage   | I <sub>GSS</sub>    | V <sub>DS</sub> = 0 V, V <sub>GS</sub> = ± 20 V  |      |      | ± 250 | nA   |
| Zero Gate Voltage Drain Current   | I <sub>DSS</sub>    | V <sub>DS</sub> = 100 V, V <sub>GS</sub> = 0 V   |      |      | 1     | μA   |
|   |                     | V <sub>DS</sub> = 150 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 125 °C  |      |      | 50    |      |
|   |                     | V <sub>DS</sub> = 150 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 150 °C  |      |      | 250   |      |
| On-State Drain Current <sup>a</sup>   | I <sub>D(on)</sub>  | V <sub>DS</sub> ≥ 10 V, V <sub>GS</sub> = 10 V   | 25   |      |       | A    |
| Drain-Source On-State Resistance <sup>a</sup>   | R <sub>DS(on)</sub> | V <sub>GS</sub> = 10 V, I <sub>D</sub> = 10 A  |      | 52   | 65    | mΩ   |
| Forward Transconductance <sup>a</sup>   | g <sub>fs</sub>     | V <sub>DS</sub> = 5 V, I <sub>D</sub> = 10 A   |      | 23   |       | S    |
| Dynamic <sup>b</sup>  |                     |  |      |      |       |      |
| Input Capacitance   | C <sub>iss</sub>    | V <sub>DS</sub> = 75 V, V <sub>GS</sub> = 0 V, f = 1 MHz   |      | 563  |       | pF   |
| Output Capacitance  | C <sub>oss</sub>    |  |      | 85   |       |      |
| Reverse Transfer Capacitance  | C <sub>rss</sub>    |  |      | 8.5  |       |      |
| Total Gate Charge <sup>c</sup>  | Q <sub>g</sub>      | V <sub>DS</sub> = 75 V, V <sub>GS</sub> = 10 V, I <sub>D</sub> = 10 A  |      | 9    |       | nC   |
| Gate-Source Charge <sup>c</sup>   | Q <sub>gs</sub>     |  |      | 2.2  |       |      |
| Gate-Drain Charge <sup>c</sup>  | Q <sub>gd</sub>     |  |      | 1.3  |       |      |
| Gate Resistance   | R <sub>g</sub>      | f = 1 MHz  |      | 4.7  |       | Ω    |
| Turn-On Delay Time <sup>c</sup>   | t <sub>d(on)</sub>  | V <sub>DD</sub> = 75 V, R <sub>L</sub> = 7.5 Ω<br>I <sub>D</sub> ≥ 10 A, V <sub>GEN</sub> = 10 V, R <sub>g</sub> = 1 Ω |      | 8    |       | ns   |
| Rise Time <sup>c</sup>  | t <sub>r</sub>      |  |      | 15   |       |      |
| Turn-Off Delay Time <sup>c</sup>  | t <sub>d(off)</sub> |  |      | 18   |       |      |
| Fall Time <sup>c</sup>  | t <sub>f</sub>      |  |      | 6    |       |      |
| Drain-Source Body Diode Ratings and Characteristics <sup>b</sup> T <sub>C</sub> = 25 °C |                     |  |      |      |       |      |
| Continuous Current  | I <sub>S</sub>      |  |      |      | 25    | A    |
| Pulsed Current  | I <sub>SM</sub>     |  |      |      | 80    |      |
| Forward Voltage <sup>a</sup>  | V <sub>SD</sub>     | I <sub>F</sub> = 1 A, V <sub>GS</sub> = 0 V  |      | 0.7  | 1.0   | V    |
| Reverse Recovery Time   | t <sub>rr</sub>     | I <sub>F</sub> = 10 A, dI/dt = 100 A/μs  |      | 34   | 51    | ns   |
| Reverse Recovery Charge   | Q <sub>rr</sub>     |  |      | 50   | 75    | nC   |

Notes:

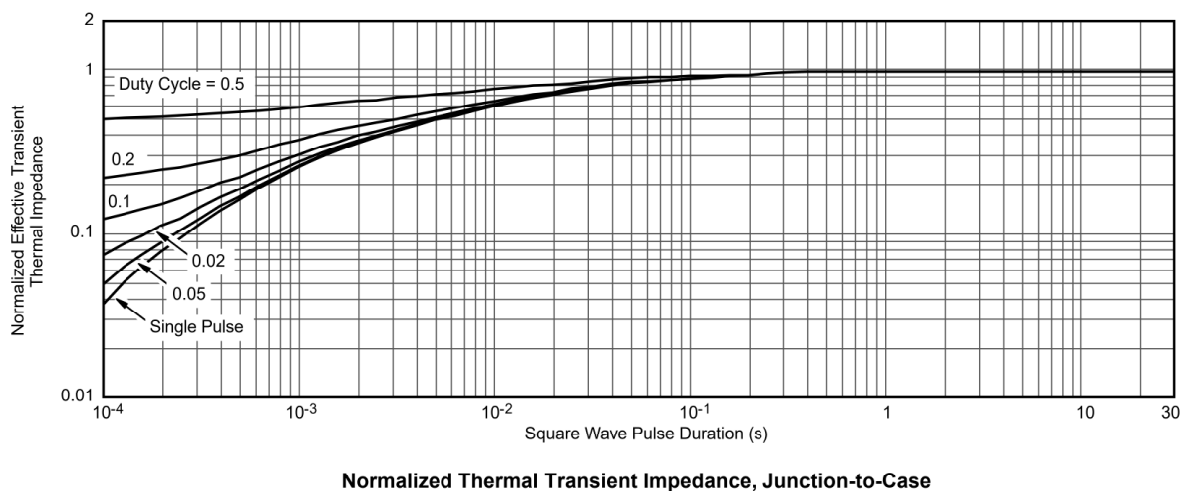
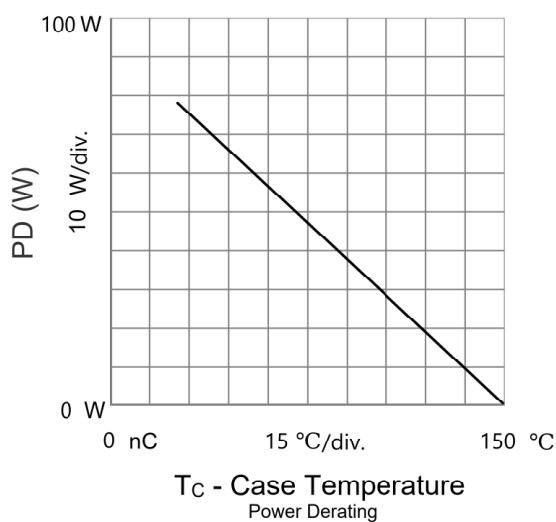
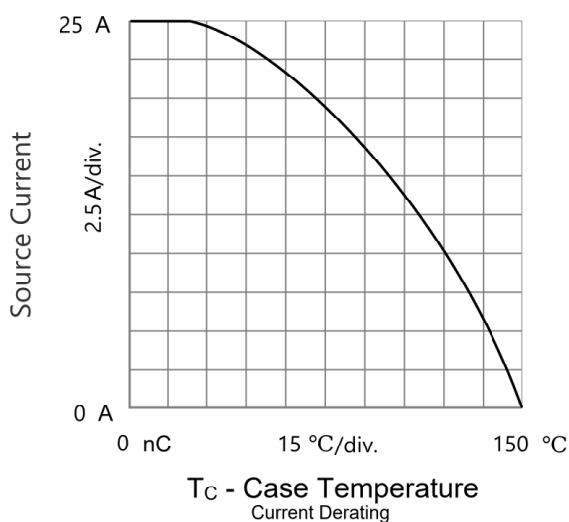
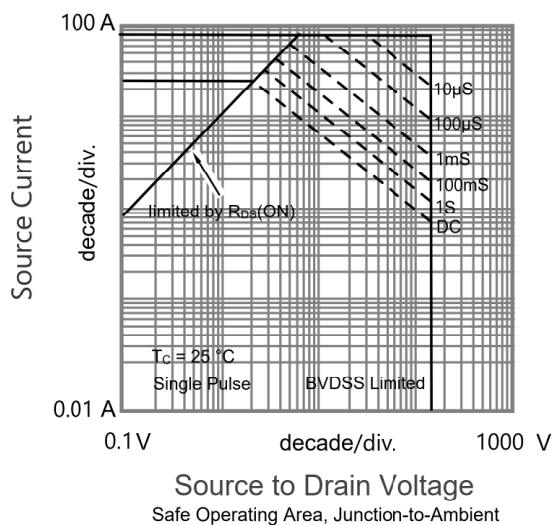
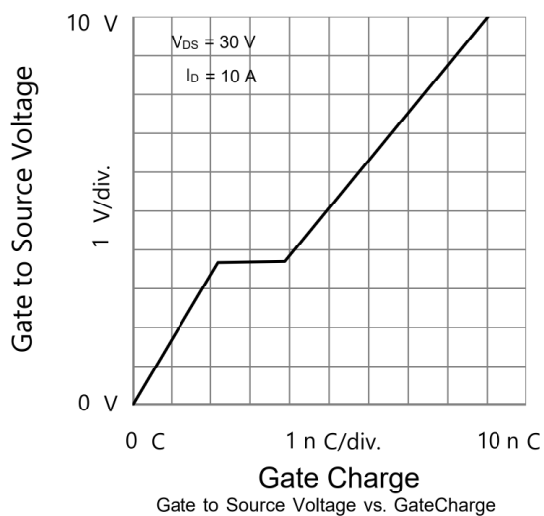
- a. Pulse test; pulse width  $\leq 300\text{ }\mu\text{s}$ , duty cycle  $\leq 2\%$ .  
 b. Guaranteed by design, not subject to production testing.  
 c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

**TYPICAL CHARACTERISTICS** (25 °C, unless otherwise noted)



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